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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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### **KSA1241**

## **Power Amplifier Applications**

- Low Collector-Emitter Saturation Voltage
- Complement to KSC3076



## **PNP Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{CBO}$	Collector-Base Voltage	- 55	V
V <sub>CEO</sub>	Collector-Emitter Voltage	- 50	V
V <sub>EBO</sub>	Emitter-Base Voltage	- 5	V
I <sub>B</sub>	Base Current	- 1	Α
I <sub>C</sub>	Collector Current	- 2	Α
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	1	W
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	10	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

### $\textbf{Electrical Characteristics} \ \textbf{T}_{\text{C}} = 25 ^{\circ} \textbf{C} \ \text{unless otherwise noted}$

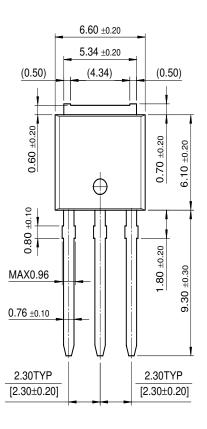
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = -10 \text{mA}, I_B = 0$	- 50			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = -50V, I_{E} = 0$			- 1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$			- 1	μΑ
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = -2V, I_{C} = -0.5A$	70		240	
h <sub>FE2</sub>		$V_{CE} = -2V, I_{C} = -1.5A$	40			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = -1A, I_B = -0.05A$			- 0.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = -1A, I_B = -0.05A$			- 1.2	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = -2V, I_{C} = -0.5A$		100		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = - 10V, f = 1MHz		40		pF
t <sub>ON</sub>	Turn ON Time	$V_{CC} = -30, I_{C} = -1A$		0.1		μs
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = -0.05A$		1		μs
t <sub>F</sub>	Fall Time	$R_L = 30\Omega$		0.1		μs

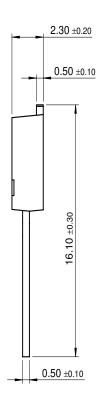
## $h_{\text{FE}}$ Classification

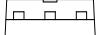
Classification	0	Y	
h <sub>FE1</sub>	70 ~ 140	120 ~ 240	

# **Package Demensions**

# I-PAK







Dimensions in Millimeters

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